Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material:	
Metal	
Overall Length:	
0.210 inches	
Terminal Length:	
0.500 inches	
Overall Diameter:	
0.230 inches	
Joint Electronic Device Engin	neering Council/jedec/case Outline Designation:
To-71	
Electrode Internally-electrica	Ily Connected To Case:
Collector	
Component Name And Quan	tity:
2 transistor	
Mounting Method:	
Terminal	
Terminal Circle Diameter:	
0.100 inches	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Silicon all transistor	
Voltage Rating In Volts Per C	characteristic:
-30.0 gate to source voltage a	Il transistor and 30.0 drain to source voltage all transistor and 30.0 drain to gate voltage all transisto
Power Rating Per Characteria	stic:
200.0 milliwatts total device dis	ssipation all transistor
Capacitance Rating In Picofa	irads:
3.0 all transistor	
Maximum Operating Tempur	ature Per Measurement Point:
125.0 degrees celsius ambient	air
Terminal Type And Quantity:	
6 uninsulated wire lead	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
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